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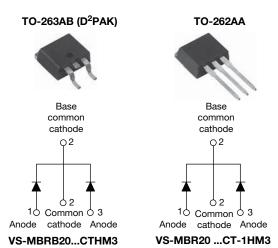






Vishay Semiconductors

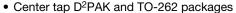
High Performance Schottky Rectifier, 2 x 10 A

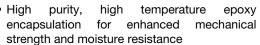


PRODUCT SUMM	PRODUCT SUMMARY						
Package	TO-263AB (D ² PAK), TO-262AA						
I _{F(AV)}	2 x 10 A						
V_{R}	80 V, 100 V						
V _F at I _F	0.70 V						
I _{RM}	6 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	24 mJ						

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation







- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform (per device)	20	^				
I _{FRM}	T _C = 133 °C (per leg)	20	A				
V _{RRM}		80 to 100	V				
I _{FSM}	t _p = 5 μs sine	850	Α				
V _F	10 A _{pk} , T _J = 125 °C	0.70	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBRB2080CTHM3 VS-MBR2080CT-1HM3	VS-MBRB2090CTHM3 VS-MBR2090CT-1HM3	VS-MBRB20100CTHM3 VS-MBR20100CT-1HM3	UNITS		
Maximum DC reverse voltage	V_{R}	80	90	100	V		
Maximum working peak reverse voltage	V_{RWM}	00	90	100	V		



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	Т	TEST CONDITIONS				
Maximum average per leg	1	T 100 °C	10				
forward current per device	I _{F(AV)}	$T_C = 133$ °C, rated V_R		20			
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 133 °C		20			
Non repetitive peak aurae aurant	_	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	850	А		
Non-repetitive peak surge current	IFSM	Surge applied at rated load conditions half wave, single phase, 60 Hz		150			
Peak repetitive reverse surge current	I _{RRM}	2.0 μs, 1.0 kHz		0.5			
Non-repetitive avalanche energy per leg	E _{AS}	$T_{J} = 25 ^{\circ}\text{C}, I_{AS} = 2$	A, L = 12 mH	24	mJ		

ELECTRICAL SPECIFICATIONS							
PARAMETER	AMETER SYMBOL TEST CONDITIONS						
		10 A	T _{.1} = 25 °C	0.80			
Maximum forward voltage drop	V (1)	20 A	1j=25 G	0.95	V		
	V _{FM} ⁽¹⁾	10 A	T 105 %C	0.70			
		20 A	T _J = 125 °C	0.85			
Manifest in the state of the st	I _{RM} ⁽¹⁾	T _J = 25 °C	Data d DO calta as	0.10	- mA		
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	6			
Threshold voltage	V _{F(TO)}	T T mayimum		0.433	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		15.8	mΩ		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	ge 100 kHz to 1 MHz), 25 °C	400	pF		
Typical series inductance	L _S	Measured from top of terr	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}~}$ Pulse width $<300~\mu s,~duty~cycle < 2~\%$

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature range		TJ		-55 to +150	°C			
Maximum storage temper	ature range	T _{Stg}		-65 to +150				
Maximum thermal resistar junction to case per leg	nce,	R _{thJC}	DC operation	2.0				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W			
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation	50				
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm (lbf · in)			
Mounting torque	maximum		Non-iubricated tilleads	12 (10)				
				MBRB20	090CTH			
Marking device			Case style D ² PAK	MBRB20	080CTH			
					100CTH			
				MBR209	0CT-1H			
			Case style TO-262	MBR208	OCT-1H			
					00CT-1H			



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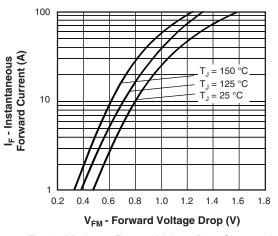


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

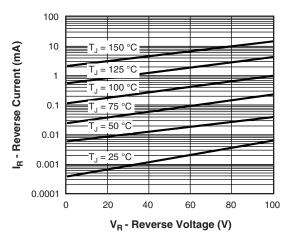


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

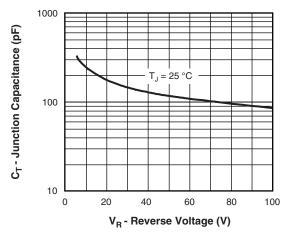


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

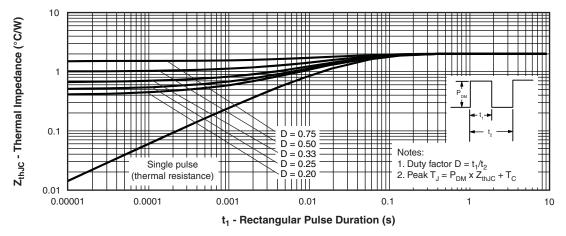


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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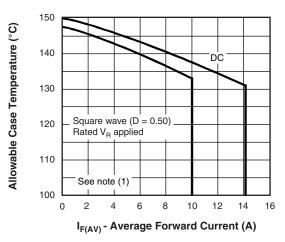


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

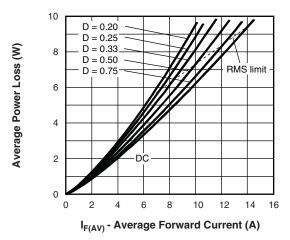


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

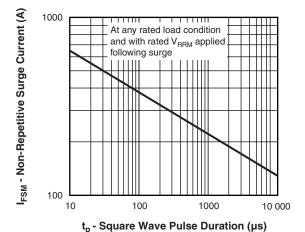


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

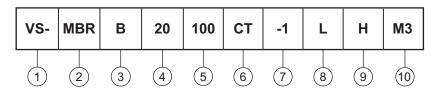
Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Essential part number

• $B = D^2PAK$ | 7 | None

• None = TO-262 7 = -1

Current rating (20 = 20 A)

80 = 80 V90 = 90 VVoltage ratings -100 = 100 V

CT = common cathode

5

• None = D^2PAK 3 = B

• -1 = TO-262 3 None

8 | • None = tube (50 pieces)

• L = tape and reel (left oriented - for D²PAK only)

• R = tape and reel (right oriented - for D²PAK only)

• H = AEC-Q101 qualified

10 • M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATI	ON (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-MBRB2080CTHM3	50	1000	Antistatic plastic tube
VS-MBRB2090CTHM3	50	1000	Antistatic plastic tube
VS-MBRB20100CTHM3	50	1000	Antistatic plastic tube
VS-MBRB2080CTLHM3	800	800	13" diameter reel
VS-MBRB2090CTLHM3	800	800	13" diameter reel
VS-MBRB20100CTLHM3	800	800	13" diameter reel
VS-MBRB2080CTRHM3	800	800	13" diameter reel
VS-MBRB2090CTRHM3	800	800	13" diameter reel
VS-MBRB20100CTRHM3	800	800	13" diameter reel
VS-MBRB2080CT-1HM3	50	1000	Antistatic plastic tube
VS-MBRB2090CT-1HM3	50	1000	Antistatic plastic tube
VS-MBRB20100CT-1HM3	50	1000	Antistatic plastic tube

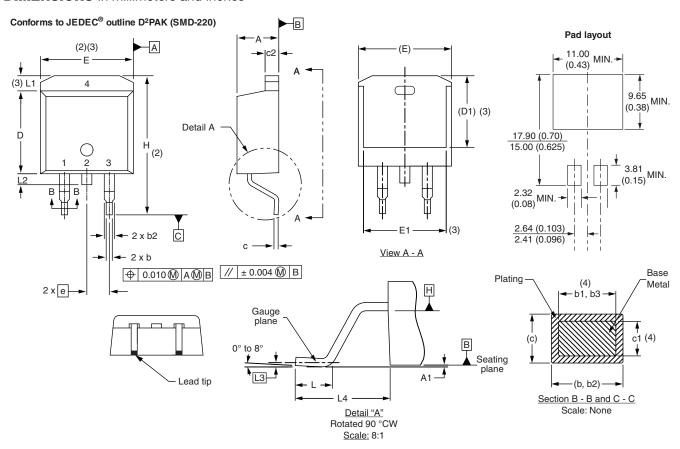
LINKS TO RELATED DOCUMENTS						
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046				
Differsions	TO-262AA	www.vishay.com/doc?95419				
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information	TO-263AB (D ² PAK)	www.vishay.com/doc?95032				



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

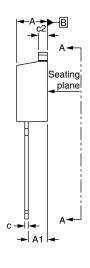


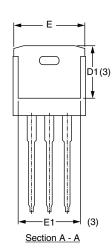
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TO-262

DIMENSIONS in millimeters and inches

-3 x b



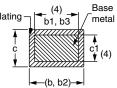


⊕ 0.010**M** A**M** B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CVMPOL	MILLIN	METERS	INCH	IES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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